

International  
**IOR** Rectifier

**10BQ060**

**SCHOTTKY RECTIFIER**

**1 Amp**

$$I_{F(AV)} = 1 \text{ Amp}$$

$$V_R = 60V$$

#### Major Ratings and Characteristics

| Characteristics                     | 10BQ060    | Units      |
|-------------------------------------|------------|------------|
| $I_{F(AV)}$ Rectangular waveform    | 1.0        | A          |
| $V_{RRM}$                           | 60         | V          |
| $I_{FSM}$ @ $t_p = 5 \mu s$ sine    | 700        | A          |
| $V_F$ @1.0 Apk, $T_J = 125^\circ C$ | 0.57       | V          |
| $T_J$ range                         | -55 to 150 | $^\circ C$ |

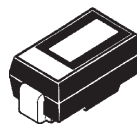
#### Description/ Features

The 10BQ060 surface-mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability

#### Case Styles

10BQ060



SMB



## Voltage Ratings

|                                                 |         |
|-------------------------------------------------|---------|
| Part number                                     | 10BQ060 |
| $V_R$ Max. DC Reverse Voltage (V)               | 60      |
| $V_{RWM}$ Max. Working Peak Reverse Voltage (V) |         |

## Absolute Maximum Ratings

| Parameters                                                 | 10BQ | Units | Conditions                                                                                                               |
|------------------------------------------------------------|------|-------|--------------------------------------------------------------------------------------------------------------------------|
| $I_{F(AV)}$ Max. Average Forward Current                   | 1.0  | A     | 50% duty cycle @ $T_L = 103^\circ\text{C}$ , rectangular wave form                                                       |
| $I_{FSM}$ Max. Peak One Cycle Non-Repetitive Surge Current | 700  | A     | 5 $\mu\text{s}$ Sine or 3 $\mu\text{s}$ Rect. pulse                                                                      |
|                                                            | 42   |       | 10ms Sine or 6ms Rect. pulse                                                                                             |
| $E_{AS}$ Non- Repetitive Avalanche Energy                  | 2.0  | mJ    | $T_J = 25^\circ\text{C}$ , $I_{AS} = 1\text{A}$ , $L = 4\text{mH}$                                                       |
| $I_{AR}$ Repetitive Avalanche Current                      | 1.0  | A     | Current decaying linearly to zero in 1 $\mu\text{sec}$<br>Frequency limited by $T_J$ max. $V_a = 1.5 \times V_r$ typical |

## Electrical Specifications

| Parameters                                                | 10BQ  | Units            | Conditions                                                            |
|-----------------------------------------------------------|-------|------------------|-----------------------------------------------------------------------|
| $V_{FM}$ Max. Forward Voltage Drop (1)<br>* See Fig. 1    | 0.6   | V                | @ 1A                                                                  |
|                                                           | 0.76  | V                | @ 2A                                                                  |
|                                                           | 0.57  | V                | @ 1A                                                                  |
|                                                           | 0.69  | V                | @ 2A                                                                  |
| $I_{RM}$ Max. Reverse Leakage Current (1)<br>* See Fig. 2 | 0.1   | mA               | $T_J = 25^\circ\text{C}$                                              |
|                                                           | 5.0   | mA               | $T_J = 125^\circ\text{C}$                                             |
| $C_T$ Typical Junction Capacitance                        | 62    | pF               | $V_R = 5V_{DC}$ (test signal range 100kHz to 1MHz) $25^\circ\text{C}$ |
| $L_S$ Typical Series Inductance                           | 2.0   | nH               | Measured lead to lead 5mm from package body                           |
| $dv/dt$ Max. Volatge Rate of Charge<br>(Rated $V_R$ )     | 10000 | V/ $\mu\text{s}$ |                                                                       |

(1) Pulse Width < 300 $\mu\text{s}$ , Duty Cycle < 2%

## Thermal-Mechanical Specifications

| Parameters                                                  | 10BQ        | Units              | Conditions       |
|-------------------------------------------------------------|-------------|--------------------|------------------|
| $T_J$ Max. Junction Temperature Range (*)                   | -55 to 150  | $^\circ\text{C}$   |                  |
| $T_{stg}$ Max. Storage Temperature Range                    | -55 to 150  | $^\circ\text{C}$   |                  |
| $R_{thJL}$ Max. Thermal Resistance Junction to Lead<br>(**) | 36          | $^\circ\text{C/W}$ | DC operation     |
| $R_{thJA}$ Max. Thermal Resistance Junction to Ambient      | 80          | $^\circ\text{C/W}$ |                  |
| wt Approximate Weight                                       | 0.10(0.003) | g(oz.)             |                  |
| Case Style                                                  | SMB         |                    | Similar DO-214AA |
| Device Marking                                              | IR1H        |                    |                  |

(\*)  $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{th(j-a)}}$  thermal runaway condition for a diode on its own heatsink

(\*\*) Mounted 1 inch square PCB

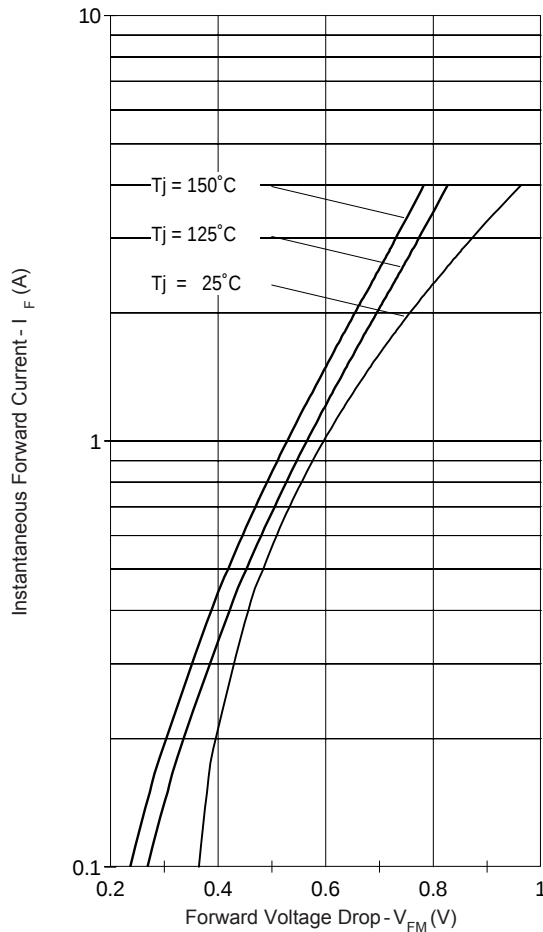


Fig. 1 - Maximum Forward Voltage Drop Characteristics

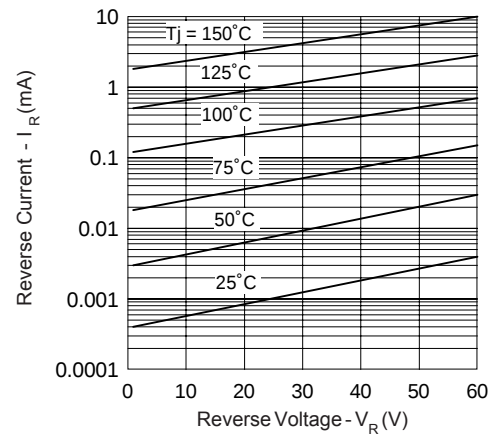


Fig. 2 - Typical Peak Reverse Current Vs. Reverse Voltage

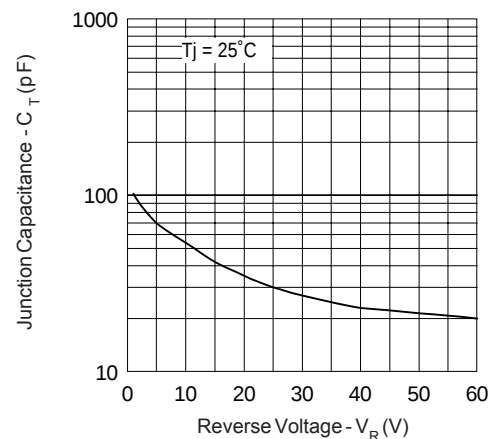


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

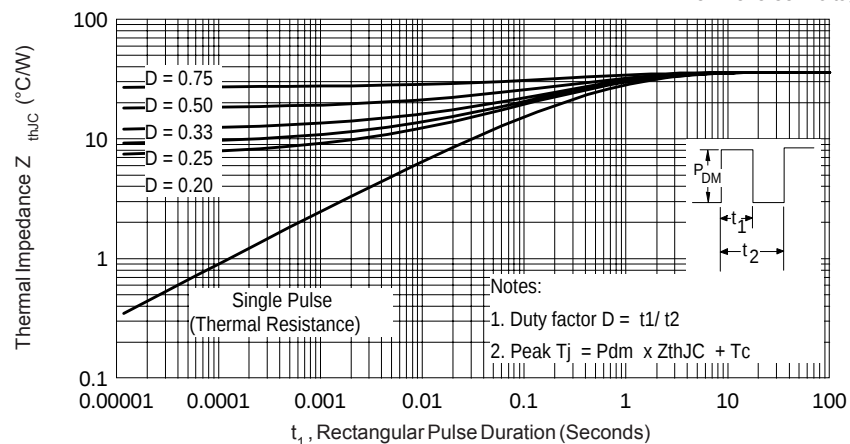


Fig. 4 - Max. Thermal Impedance  $Z_{thJC}$  Characteristics (Per Leg)

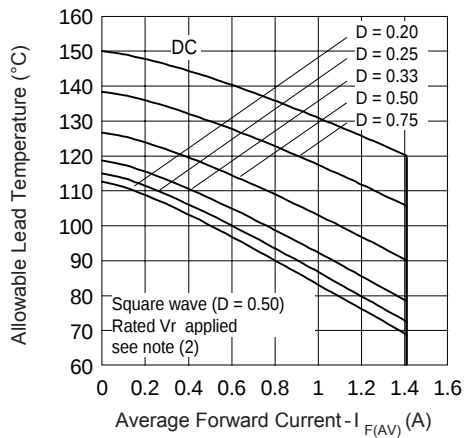


Fig. 4 - Maximum Average Forward Current Vs. Allowable Lead Temperature

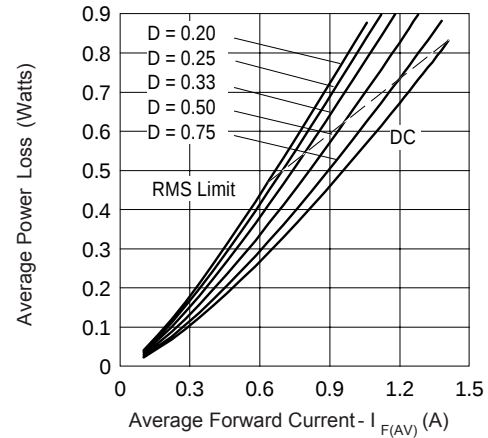


Fig. 5 - Maximum Average Forward Dissipation Vs. Average Forward Current

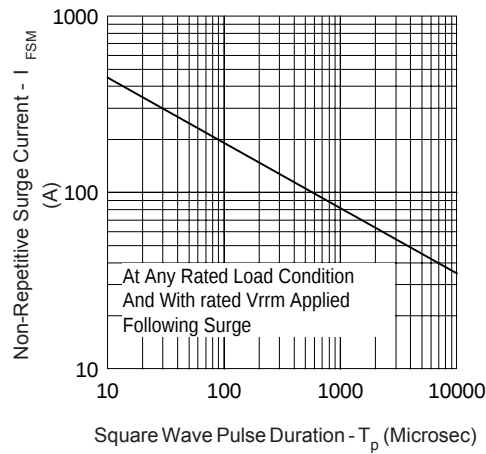


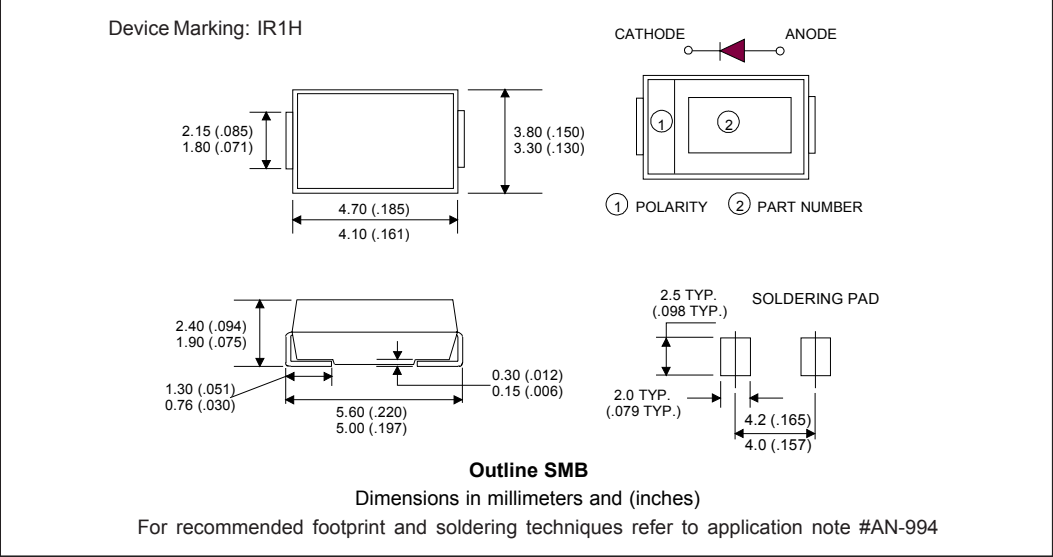
Fig. 6 - Maximum Peak Surge Forward Current Vs. Pulse Duration

(2) Formula used:  $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$ ;

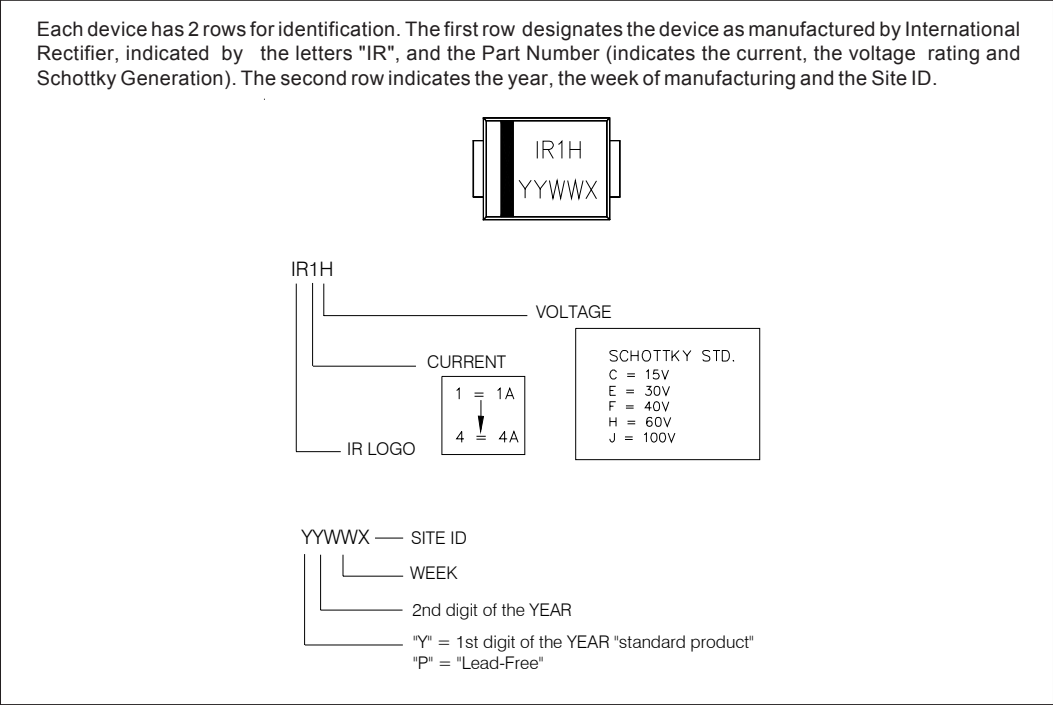
$P_d$  = Forward Power Loss =  $I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$  (see Fig. 6);

$P_{d_{REV}}$  = Inverse Power Loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R @ V_{R1} = 80\% \text{ rated } V_R$

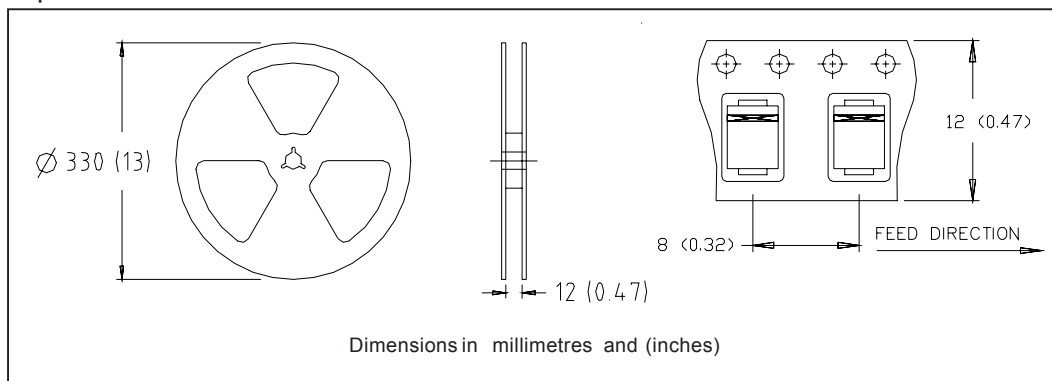
Outline Table



Marking & Identification



## Tape &amp; Reel Information



## Ordering Information Table

| Device Code |   |   |     |    |   |
|-------------|---|---|-----|----|---|
| 10          | B | Q | 060 | TR | - |
| ①           | ② | ③ | ④   | ⑤  | ⑥ |
| 1           | - | - | -   | -  | - |
| 2           | - | - | -   | -  | - |
| 3           | - | - | -   | -  | - |
| 4           | - | - | -   | -  | - |
| 5           | - | - | -   | -  | - |
| 6           | - | - | -   | -  | - |

- 1 - Current Rating
- 2 - B = Single Lead Diode
- 3 - Q = Schottky Q Series
- 4 - Voltage Rating (060 = 60V)
- 5 -
  - none = Box (1000 pieces)
  - TR = Tape & Reel (3000 pieces)
- 6 -
  - none = Standard Production
  - PbF = Lead-Free

Data and specifications subject to change without notice.  
This product has been designed and qualified for Industrial Level.  
Qualification Standards can be found on IR's Web site.

International  
**IR** Rectifier

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